	Type	L #	Hits	Search Text	DBs
1	IS&R	L7	1603	(327/108).CCLS.	US-PGPUB; USPAT
2	BRS	L8	700	7 and (comparator amplifier) and transistor	US-PGPUB; USPAT
3	BRS	L9	677	327/112.ccls.	US-PGPUB; USPAT
4	BRS	L10	298	9 and (comparator amplifier) and transistor	US-PGPUB; USPAT
5	BRS	L11	217	10 not 8	US-PGPUB; USPAT
6	IS&R	L12	162	(327/323).CCLS.	US-PGPUB; USPAT
7	IS&R	L13	177	(327/404).CCLS.	US-PGPUB; USPAT
8	BRS	L14	20586	transistor.ti. and (comparator amplifier)	USOCR; EPO; JPO; DERWENT; IBM_TDB
9	BRS	L15	2902	14 and sens$3	USOCR; EPO; JPO; DERWENT; IBM_TDB
10	BRS	L16	1103	15 and (resistor diode)	USOCR; EPO; JPO; DERWENT; IBM_TDB
11	IS&R	L17	531	(361/93.1).CCLS.	US-PGPUB; USPAT
12	BRS	L18	164	17 and (comparator amplifier) and transistor	US-PGPUB; USPAT
13	BRS	L19	3662	current near2 protect$3.ti.	USOCR; EPO; JPO; DERWENT; IBM_TDB
14	BRS	L20	547	19 and (amplifier comparator)	USOCR; EPO; JPO; DERWENT; IBM_TDB
15	IS&R	L22	322	(361/93.9).CCLS.	US-PGPUB; USPAT
16	BRS	L25	3664	current near2 protect$5.ti.	USOCR; EPO; JPO; DERWENT; IBM_TDB
17	BRS	L26	606	25 and transistor	USOCR; EPO; JPO; DERWENT; IBM_TDB
18	BRS	L27	3010	overcurrent near2 protect$5.ti.	USOCR; EPO; JPO; DERWENT; IBM_TDB
19	BRS	L28	739	27 and transistor	USOCR; EPO; JPO; DERWENT; IBM_TDB
20	BRS	L29	21790	transistor same (amplifier comparator) same (sens$3 detect$3) same (resistor diode)	US-PGPUB; USPAT
21	BRS	L30	1139	29.clm.	US-PGPUB; USPAT
22	BRS	L31	600	30 same current	US-PGPUB; USPAT
23	IS&R	L34	762	(327/427).CCLS.	US-PGPUB; USPAT
24	BRS	L35	402	34 and diode	US-PGPUB; USPAT